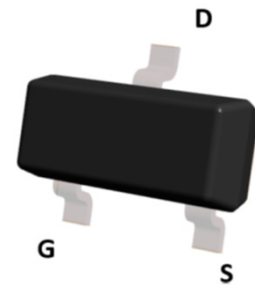
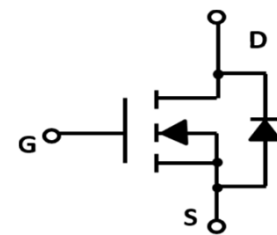
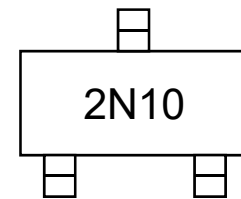


Description

The MOSFET provide the best combination of fast switching , low on-resistance and cost-effectiveness.

- Trench Power MV MOSFET technology
- Voltage controlled small signal switch
- Low input Capacitance
- Fast Switching Speed
- Low Input / Output Leakage


Top View

Circuit Diagram

Marking (Top View)

MOSFET Product Summary		
$V_{DS}(V)$	$R_{DS(on)}(m\Omega)$	$I_D(A)$
100	$280@V_{GS} = 10V$	2
	$400@V_{GS} = 4.5V$	

Mechanical Data

- SOT-23 Small Outline Plastic Package.
- Epoxy UL: 94V-0.
- Mounting Position: Any.

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Drain-source Voltage	V_{DS}	100	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current	I_D	2.0	A
Continuous Source-Drain Diode Current	I_S	1.1	A
Pulsed Source Current	I_{SM}	7.0	A
Total Power Dissipation	P_D	400	mW
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	312.5	$^{\circ}C/W$
Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{STG}	-55~+150	$^{\circ}C$

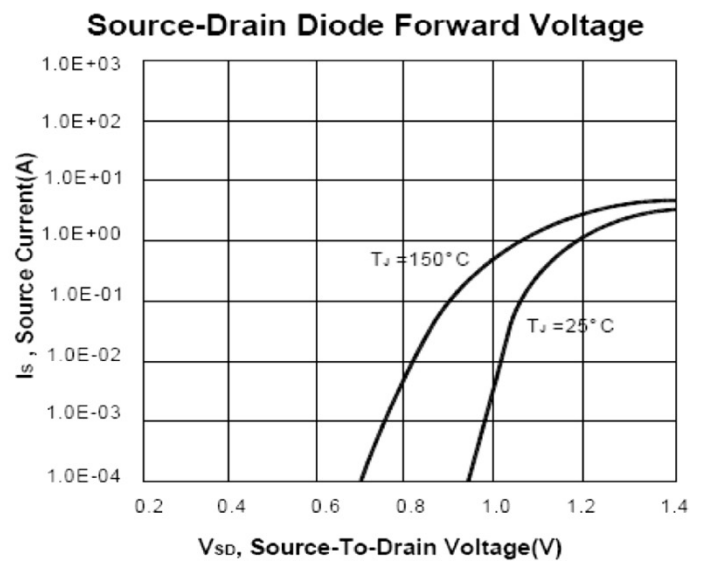
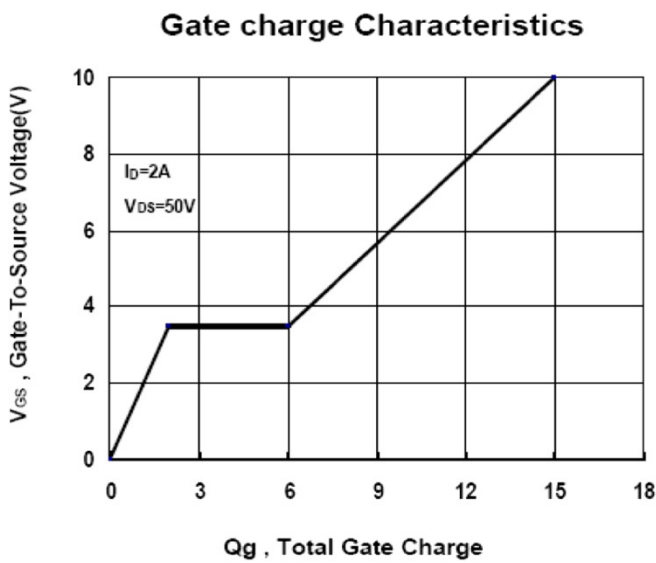
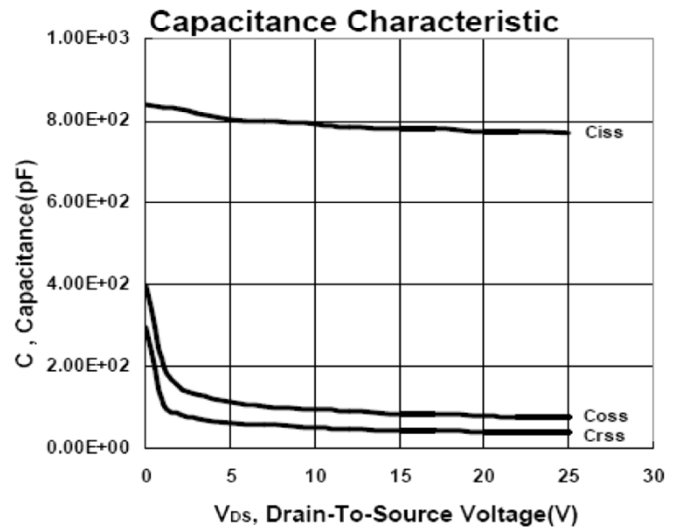
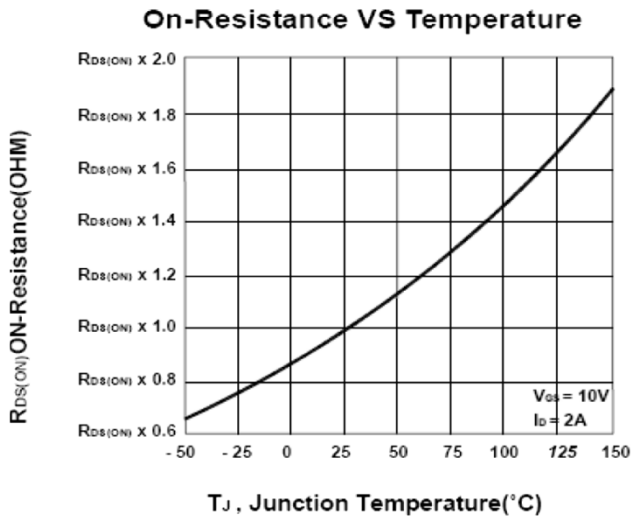
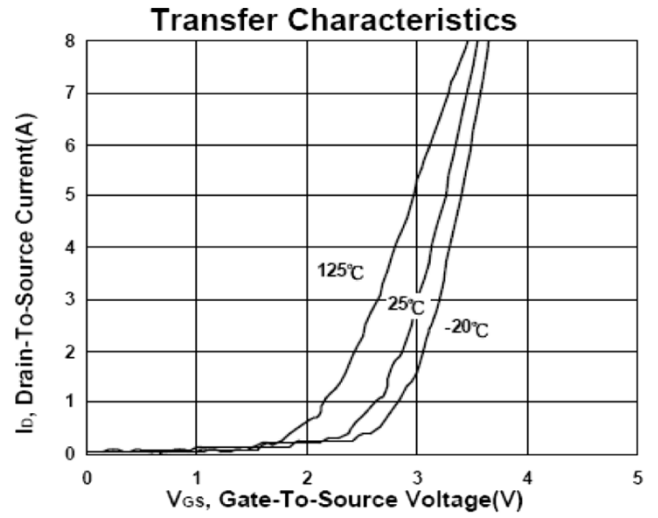
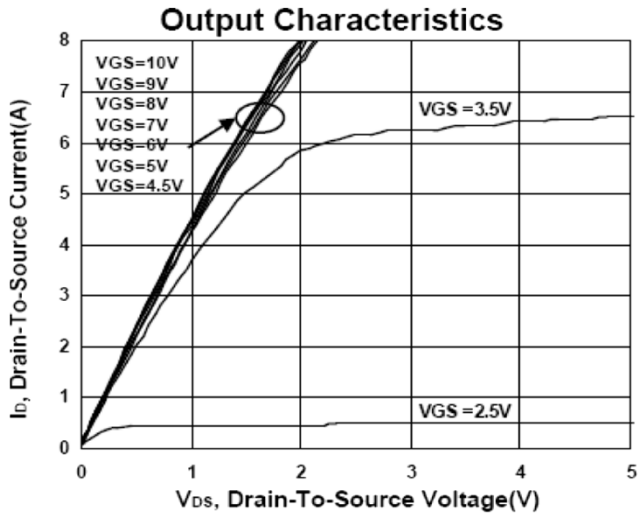
Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	100	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 80V, V_{GS} = 0V$	-	-	1.0	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.8	0.95	1.6	V
Static Drain-Source On-Resistance ¹⁾	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 1.5A$	-	220	280	m Ω
		$V_{GS} = 4.5V, I_D = 1A$	-	300	400	
Forward Transconductance ¹⁾	g_{fs}	$V_{DS} = 50V, I_D = 1.6A$	5.7	-	-	S
Diode Forward Voltage	V_{SD}	$I_S = 1.1A, V_{GS} = 0V$	-	-	1.3	V
Dynamic Parameters						
Input Capacitance ²⁾	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1MHz$	-	290	-	pF
Output Capacitance ²⁾	C_{oss}		-	27	-	
Reverse Transfer Capacitance ²⁾	C_{rss}		-	13	-	
Total Gate Charge	Q_g	$V_{DS} = 50V, I_D = 1.6A,$ $V_{GS} = 4.5V$	-	2.5	-	nC
Gate-Source Charge	Q_{gs}		-	0.5	-	
Gate-Drain Charge	Q_{gd}		-	1.2	-	
Switching Parameters²⁾						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 50V, V_{GS} = 4.5V,$ $R_G = 6.8\Omega, I_D = 1A$	-	2.2	-	ns
Turn-on Rise Time	t_r		-	2.1	-	
Turn-Off Delay Time	$t_{d(off)}$		-	9.0	-	
Turn-Off Fall Time	t_f		-	3.6	-	

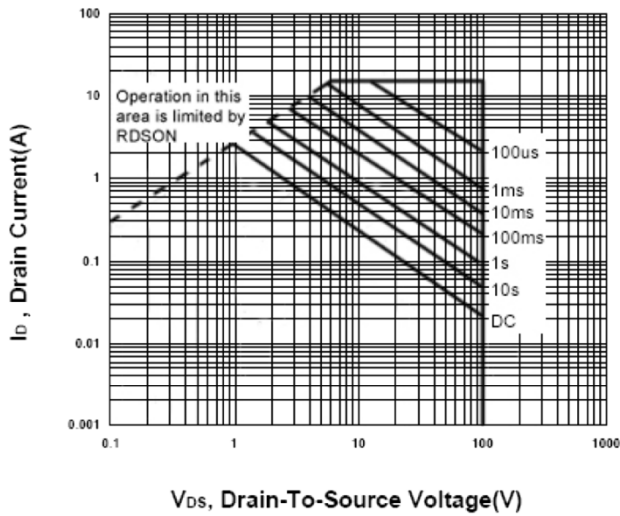
Notes:

- Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- These parameters have no way to verify.

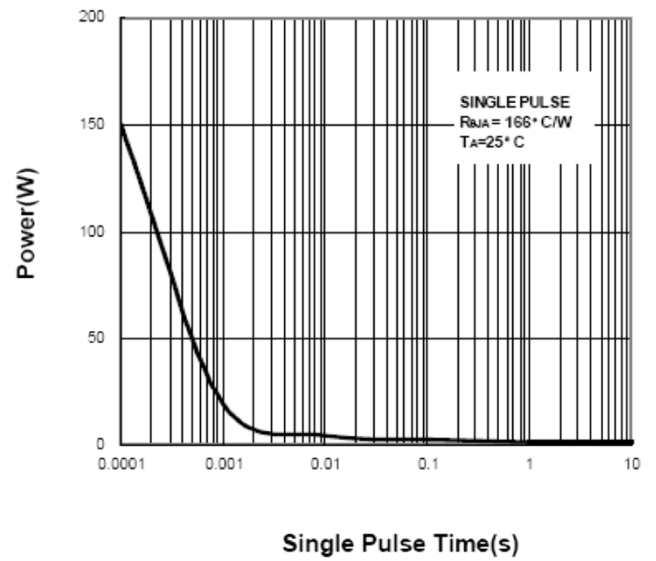
Typical Characteristics



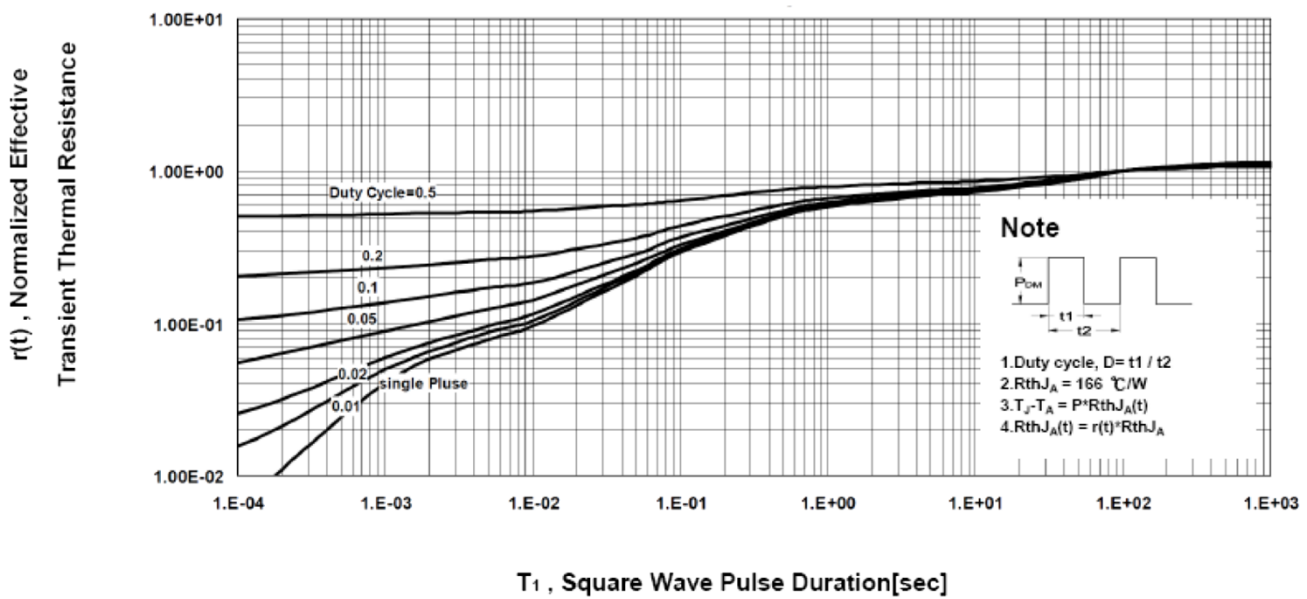
Safe Operating Area



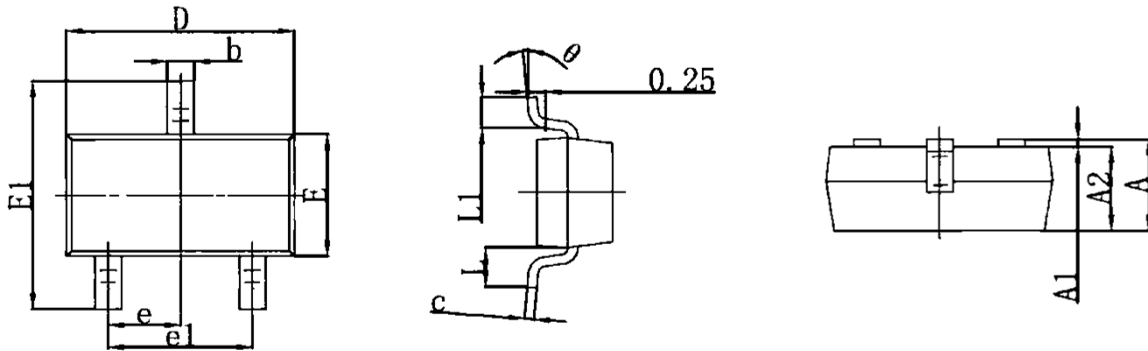
Single Pulse Maximum Power Dissipation



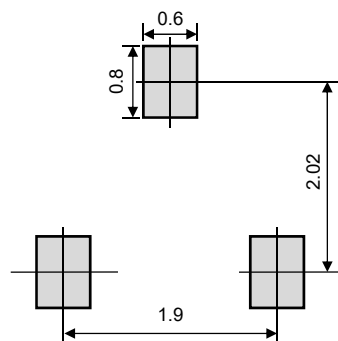
Transient Thermal Response Curve



Product Dimension (SOT-23)



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	-	1.50	-	0.059
A1	0.04	0.15	0.002	0.006
A2	-	1.35	-	0.053
b	0.30	0.50	0.012	0.020
c	0.08	0.21	0.003	0.008
D	2.72	3.12	0.107	0.123
E	1.10	1.50	0.043	0.059
E1	2.10	2.64	0.083	0.104
e	0.95 Typ.		0.037 Typ.	
e1	1.80	2.00	0.071	0.079
L	0.65 Ref.		0.026 Ref.	
L1	0.20	0.60	0.008	0.024
θ	0°	8°	0°	8°



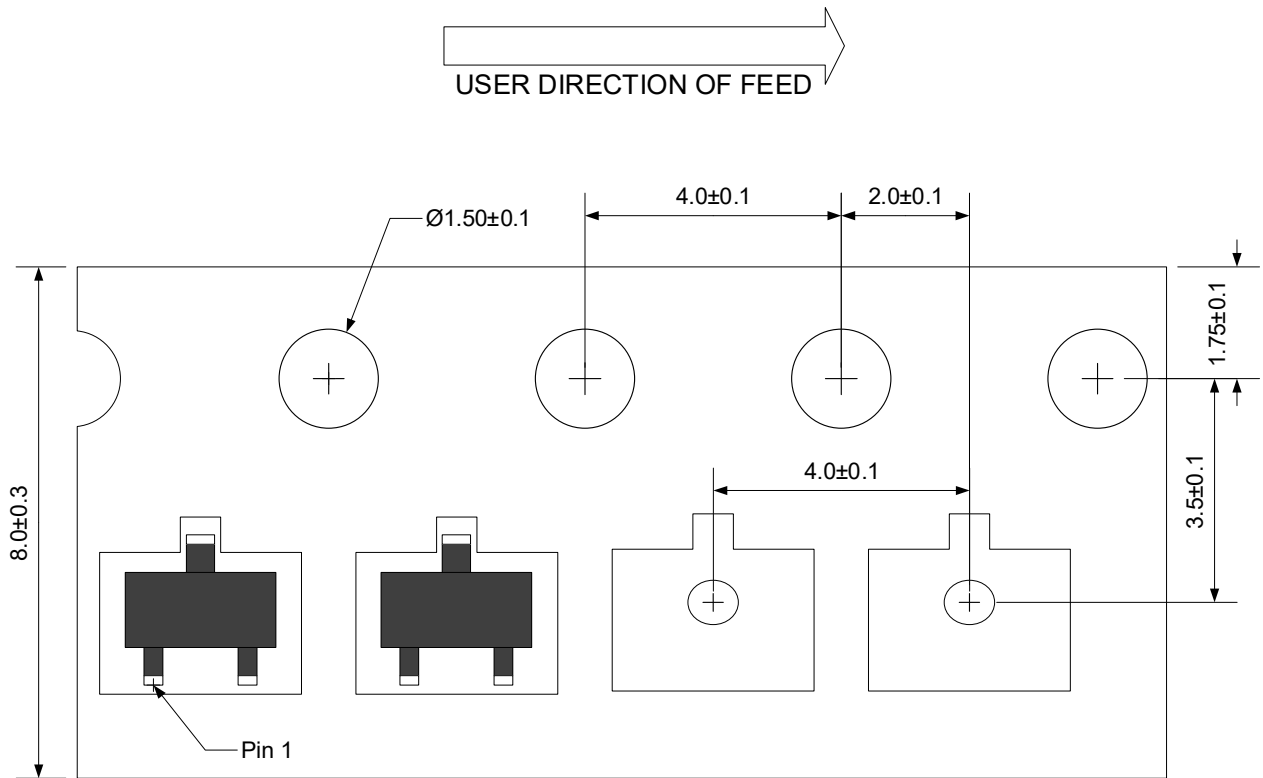
Suggested PCB Layout

Unit: mm

Ordering information


Device	Package	Reel	Shipping
PNMT100V2	SOT-23	7"	3000 / Tape & Reel

Load with information



Unit:mm


IMPORTANT NOTICE

 and **Prisemi**[®] are registered trademarks of **Prisemi Electronics Co., Ltd** (Prisemi), Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. “Typical” parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: <http://www.prisemi.com>

For additional information, please contact your local Sales Representative.

©Copyright 2009, Prisemi Electronics

 **Prisemi**[®] is a registered trademark of Prisemi Electronics.

All rights are reserved.